Unit: mm



TOSHIBA Insulated Gate Bipolar Transistor Silicon N Channel IGBT

GT8G134

Strobe Flash Applications

- Compact and Thin (TSSOP-8) package
- Enhancement-mode
- Peak collector current: Ic = 150 A (max)

(@V_{GE}=2.5V(min))/

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	400	V	
Cata amilitari valtara	DC	V _{GES}	± 4	V	
Gate-emitter voltage	Pulse	V _{GES}	± 5	V	
Collector current	Pulse (Note 1)	I _{CP}	150	Α	
Collector power	(Note 2a)	P _C (1)	1.1	W	
dissipation (t=10 s)	(Note 2b)	P _C (2)	0.6	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

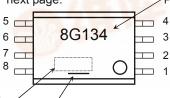
Please design the appropriate reliability upon reviewing the Semiconductor Reliability Handbook Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate,

Thermal Characteristics

Characteristics	Symbol	Rating	Unit	
Thermal resistance , junction to ambient (t = 10 s) (Note2a)	R _{th (j-a)} (1)	114	°C/W	
Thermal resistance , junction to ambient (t = 10 s) (Note2b)	R _{th (j-a)} (2)	208	°C/W	

Marking (Note 3)

Note: For (Note 1), (Note 2a), (Note 2b) and (Note 3), Please refer to the next page. Part No. (or abbreviation code)

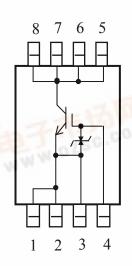


A line indicates lead (Pb)-free package or lead (Pb)-free finish.

TSSOP-8 Ø 0.05 **EMITTER EMITTER (Gate drive connection)** GATE 5,6,7,8 COLLECTOR **JEDEC** JEITA **TOSHIBA**

Weight: 0.035 g (typ.)

Circuit Configuration



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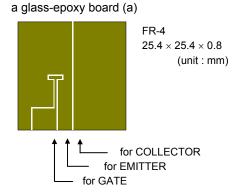
Electrical Characteristics (Ta = 25°C)

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curr	ent	I _{GES}	$V_{GE} = \pm 4 \text{ V}, V_{CE} = 0$	_	_	± 10	μΑ
Collector cut-off c	urrent	I _{CES}	V _{CE} = 400 V, V _{GE} = 0	_	_	10	μА
Gate-emitter cut-o	off voltage	V _{GE} (OFF)	I _C = 1 mA, V _{CE} = 5 V	0.65	1.0	1.35	V
Collector-emitter	saturation voltage	V _{CE} (sat)	I _C = 150 A, V _{GE} = 2.5 V		3.4	_	V
Input capacitance		C _{ies}	$V_{CE} = 10 \text{ V}, V_{GE} = 0, f = 1 \text{ MHz}$		4560	_	pF
Switching time	Rise time	t _r	$\begin{array}{c} 3 \text{ V} \\ 0 \\ \hline \\ \text{V}_{\text{IN}} \text{: } t_r \leq 100 \text{ ns} \\ \text{t}_f \leq 100 \text{ ns} \\ \text{Duty cycle} \leq 1\% \\ \end{array} \\ \begin{array}{c} 62 \Omega \\ \hline \\ \approx 300 \text{ V} \\ \hline \\ \Rightarrow 300 \text{ V} \\ \hline \end{array}$		0.6	_	
	Turn-on time	t _{on}			0.8	_	6
	Fall time	t _f			1.2	_	μS
	Turn-off time	t _{off}		_	1.8	_	

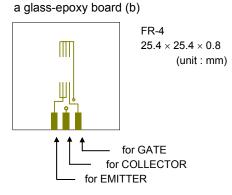
Note

Note 1: Please use devices on condition that the junction temperature is below 150°C. Repetitive rating: pulse width limited by maximum junction temperature.

Note 2a : Device mounted on



Note 2b : Device mounted on



Note 3: O on lower right of the marking indicates Pin 1.

※	Weekly code:	(Three digits)
		eek of manufacture 1 for first week of year, continues up to 52 or 53)
	Y€	ear of manufacture one low-order digits of calendar year)

Pb-Free Finish (Only a coating lead terminal) :

It is marking about an underline to a week of manufacture mark.



Caution on handling

This device is MOS gate type. Therefore , please care of a protection from ESD in your handling .

Caution in design

You should be design dV/dt value under Icp=150A is below 400 V/ μ s when IGBT turn off under Ta=70 $^{\circ}$ C . You should be design to don't flow collector current through terminal number 3 .

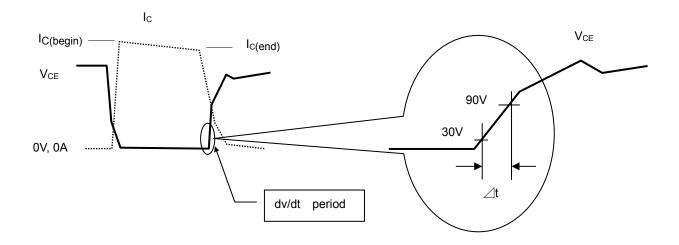
definition of dv/dt

The slope of V_{CE} from 30v to 90v (attached figure.1)

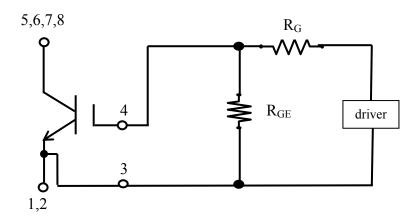
$$dv/dt = (90V-30V) / (\triangle t)$$
$$= 60V / \triangle t$$

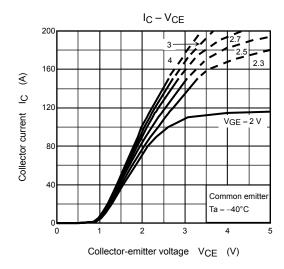
waveform

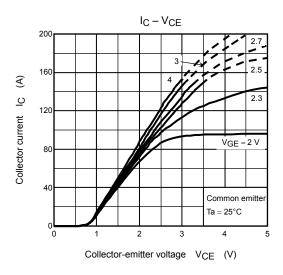
waveform (expansion)

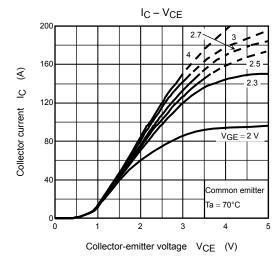


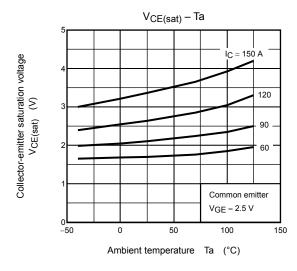
Gate drive connection

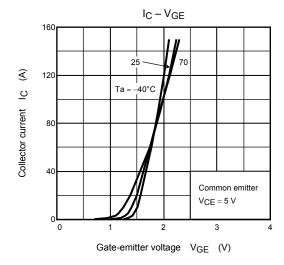


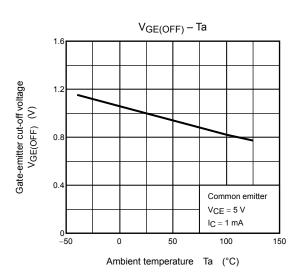


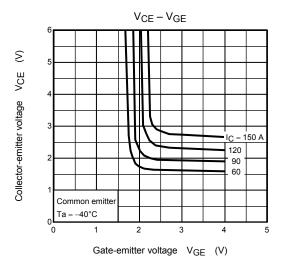


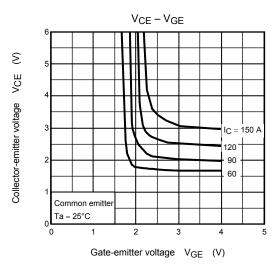


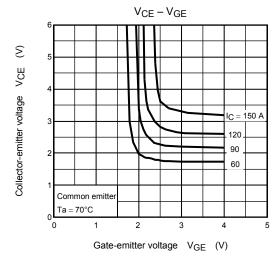


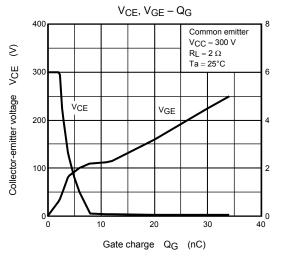




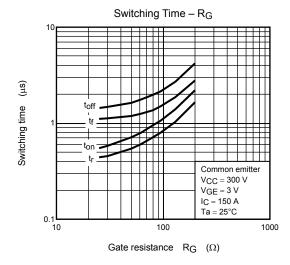


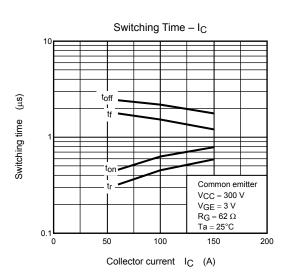


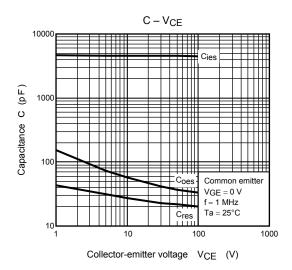


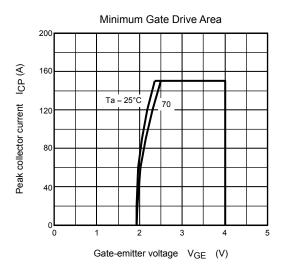


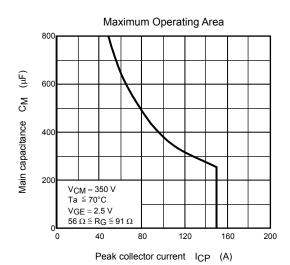












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